# Photoelectrochemical Generation of Hydrogen from Water Using Visible Light Sensitive Ferro-Electric BiFeO<sub>3</sub> and Semiconductor Nanotubes

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April 21, 2010

Project ID # PD 076

DOE Hydrogen Program Review 2010

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# **Overview**

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Timeline	Barriers	
<ul> <li>Project start date: October, 2006</li> <li>Project end date: September, 2010</li> <li>Percent complete: 90</li> </ul>	<ul> <li>Barriers addressed:         <ul> <li>AP. Materials efficiency</li> <li>AQ. Materials durability</li> <li>AR. Bulk material synthesis</li> <li>AS. Device configuration and scale up</li> </ul> </li> </ul>	
Budget	Partners	

# **Objectives**

Overall	Develop high efficiency hybrid-semiconductor nanotubular materials for hydrogen generation by water splitting
2006-2007	<ul> <li>Develop new anodization technique to synthesize high quality and robust TiO<sub>2</sub> nanotubes with wide range of nanotubular architectures</li> <li>Develop low band gap TiO<sub>2</sub> nanotubes</li> <li>Understand kinetics and formation mechanism of the titanium dioxide nanotubes under different synthesis conditions</li> </ul>
2007-2008	<ul> <li>Develop organic-inorganic hybrid photo-anodes</li> <li>Develop combinatorial approach to synthesize hybrid photo-anodes having multiple semiconductors in a single photo-anode</li> <li>Develop cost-effective cathode materials</li> </ul>
2008-2009 2009-2010	<ul> <li>Develop mixed metal oxide nanotubular photo-anodes</li> <li>Develop multi-junction photoanodes</li> <li>Design PEC systems for on-field testing under real solar irradiation</li> <li>Develop semiconductors which absorb in the visible region of the solar spectrum</li> </ul>
2010-2011	<ul> <li>Develop QD-nanotubular oxide hybrid photo-anodes based on DFT modeling</li> </ul>

# Approach

### Task A. Synthesis and fabrication of metal oxide and oxynitride nanotube arrays

Ultrasonic mediated metal (Fe and Ta) oxide nanotube arrays (NTs) Fabrication and process development of one dimensional oxynitride arrays Low cost sol-gel based synthesis of BiFeO<sub>3</sub> ferro-electric photo catalysts Characterization and fundamental understanding of the materials prepared

# Task B. Application of the nanotubular materials for photo-electrochemical generation of H<sub>2</sub> from Water

Evaluate photo-electrochemical behavior of nanotubular oxide photoanodes

Evaluate photo catalytic and photo electrochemical behaviors of BiFeO<sub>3</sub>

### Task C. Materials stability of hybrid oxide nanotubular photo-anodes

Electrochemical methods Spectroscopic and Electron Microscopic analyses

#### Task D. Scale-up and process evaluation.

Scale-up of photoanodes Photoelectrochemical hydrogen generation under real solar irradiation

### Task E. First Principle Modeling of Semiconductors for harvesting visible light

# Synthesis of high-quality, low band gap, BiFeO<sub>3</sub> nanoparticles as photo catalytic materials

Major Challenge of Conventional Photo Catalysts: Low Photo Conversion Efficiency
An internal electric field is required for effective separation of electrons and holes.
In semiconductor photo catalytic materials, the internal electric field exists only at the interfaces.
Charge is transported mainly by a slow diffusion process in the bulk of the material that results in low photo conversion efficiency

UNR Approach: Ferro-electric Photo catalysts

An internal electric field exists across the bulk of the ferro-electric material because of a low-symmetry state;

This high internal electric field helps effectively separate photo induced charge carriers in the ferroelectric materials;

Generation of photo potential in the ferroelectric material is not limited by its band gap or magnitude of band bending at the interfaces;

High ferroelectric polarization of the material results in high photo induced potentials.

#### **Barriers**

Very low photo current densities due to large bandgap (>3.5 eV) and poor dc conduction

Solution

Development of band gap engineered nanoscale ferro-electric materials

# Synthesis of BiFeO<sub>3</sub> Ferro-electric Photo Catalyst



(a) 50nm 10 m 10 m 10 m 10 m

Flow diagram of sol-gel synthesis of  $BiFeO_3$  nano-particles

TEM images of BiFeO<sub>3</sub> calcined at 600 °C for 2 h under N<sub>2</sub> atmosphere

## Characterization of BiFeO<sub>3</sub> Ferro-electric Photo Catalyst





XRD patterns of BiFeO<sub>3</sub> annealed under N<sub>2</sub> at 600 °C for (a) 15 min, (b) 30 min, (c) 1 h, (d) 4 h and (e) 2 h

Band gap 2.1 eV

UV-Vis absorption spectrums of BiFeO<sub>3</sub> and BaTiO<sub>3</sub>; The inset shows the BiFeO<sub>3</sub> plot of  $(\alpha h\nu)^2$  as a function of photon energy



SP-GGA+U is used for calculation of the band structure and optical properties of  $BiFeO_3$ , considering the unoccupied Fe 3d orbital state. The calculated band gap is 1.61 eV.

# Hydrogen Generation using BiFeO<sub>3</sub> Ferro-electric Photo Catalyst in 1 M KOH under AM 1.5 Light Illumination



# Theoretical investigation of the formation of TaON from $Ta_2O_5$ NTs by density functional theory

The first principle computational calculations of Ta<sub>2</sub>O<sub>5</sub> and TaON were carried out based on density functional theory (DFT) using plane wave assumption
CASTEP program in Materials Studio® supplied by Accelrys® is the computational platform



Crystal structures of (a)  $Ta_2O_5$  and (b)  $\gamma$ -TaON

# Theoretical investigation of the formation of TaON from $Ta_2O_5$ NTs by density functional theory



Partial density of states as a function of energy level of (a)  $Ta_2O_5$  and (b)  $\gamma$ -TaON. The calculated band gaps are smaller than the experimentally determined values.

In our current simulation, the calculated band gap of  $Ta_2O_5$  is 3.6eV, while the experimental value is 4 eV.

The calculated band gap of  $\gamma$ -TaON is about 1.9 eV.

## Optical absorbance spectra of $Ta_2O_5$ and $\gamma$ -TaON



Calculated UV-Vis optical absorbance spectra of Ta<sub>2</sub>O<sub>5</sub> and TaON and extrapolated band-gap values.

TaON.

The calculated optical absorbance spectra follow a similar trend of the experimentally determined optical absorbance of anodic Ta<sub>2</sub>O<sub>5</sub> and transformed TaON nanotubes.

## Synthesis of Tantalum Oxynitride (TaON) Nanotubes





SEM images of  $Ta_2O_5$  nanotube arrays on Ta foil. The insets show the cross sectional image of  $Ta_2O_5$  NT arrays of 525 nm and bottom of the nanotubes

**Anodizing solution:** Ethylene glycol + water + NH<sub>4</sub>F

### Formation mechanism:

2Ta + 5H<sub>2</sub>O  $\rightarrow$  Ta<sub>2</sub>O<sub>5</sub>(anodic) + 5H<sub>2</sub>(cathodic)  $\uparrow$  (1) Ta<sub>2</sub>O<sub>5</sub> + 12F<sup>-</sup> + 10H<sup>+</sup>  $\rightarrow$  2[TaF<sub>6</sub>]<sup>-</sup> + 5H<sub>2</sub>O (2)

#### **Characteristics:**

525nm long in just 2 minutes
50 ± 5 nm internal tube diameter

# Synthesis of Tantalum Oxynitride (TaON) Nanotubes



**Fig.** SEM image of TaON nanotube arrays on Ta foil. The morphology is same as  $Ta_2O_5$  NTs

### NT arrays are stable after nitridation

Fig. TEM image of TaON nanotube arrays

### NTs are highly crystalline

### Synthesis of Tantalum Oxynitride (TaON) Nanotubes



Fig. DRUV-Vis spectra of  $Ta_2O_5$  and TaON NTs

# Band gap: 2.07 eV

Absorption band-edge of TaON is at ca. 600 nm, being shifted by about
 300 nm from that of Ta<sub>2</sub>O<sub>5</sub>

Band gap: 2.07 eV Ideal band gap the photosplitting of water

Band edge (literature, sol-gel process): 500 nm

➢ Red shift of 100 nm (from 500nm to 600 nm) : May be due to a) presence of carbon in the as-anodized Ta<sub>2</sub>O<sub>5</sub> nanotubular sample. b) The sample is nanotubular. However, this strange behavior is not clear yet and further investigations are necessary

## Photoelectrolysis Using TaON NTs and Pt cathode



Table. Comparison of photocurrent density of TaON NTs with various other photocatalysts

Catalyst	Photocurrent density (mA/cm <sup>2</sup> ) <sup>a</sup> at 0.5 V <sub>Ag/AgCI</sub>	Visible light contribution (%) <sup>b</sup>
P25/Ti	0.365	0.32
TiO <sub>2</sub> NTs/Ti	0.638	0.39
$Fe_2O_3$ NTs/Fe	1.4	50
$Fe_2O_3$ nanoparticle/Fe	0.004	NA
$Ta_2O_5$ NTs/Ta	0.25	0.28
TaON NTs/Ta	2.6	47

# Summary

- Relevance: Develop a stable and efficient photoelectrochemical cell for solar hydrogen generation by water splitting
- Approach: Synthesize visible light sensitive nanotube arrays as photoanode and ferro-electric photo catalysts for improved photo conversion process
- Technical accomplishments and process: Developed ultra-thin TaON nanotube arrays with band gap around 2 eV with 40-50% visible light activity and a low-cost process for synthesis of nanostructured BiFeO<sub>3</sub> ferro-electric photo catalyst.
- Technology transfer/collaboration: Active partnership with NREL and University of Arkansas at Little Rock.
- Proposed future research: (a) Synthesize QD-sensitized photoanodes that can harvest full spectrum of sunlight based on first-principle calculations, (b) theoretical and experimental investigations on the ferro-electric photo catalytic materials, (c) scale-up the PEC system, and (d) on-field testing under real solar irradiation.

### **Future Work**

**\***Synthesis of visible light sensitive QD sensitized photoanodes based on the DFT calculations

**\***Optimize synthesis process of TaON NTs and ferro-electric photocatalysts

Increase charge transport properties of BiFeO<sub>3</sub>

**\***Kinetics studies of nanotubes formation by titration using spectrophotometric analysis

Incident photon to current conversion efficiency (IPCE) measurements
 Scale-up the system

**\***Design PEC system for on-field testing under real solar irradiation.

✤Fundamental understanding of TaON formation from Ta<sub>2</sub>O<sub>5</sub> structure, and structural, electronic, and optical properties of various TaON polymorphs

To understand the ordering of oxygen vacancies and their role on charge transport properties and recombination losses in oxide and oxynitride semiconductors